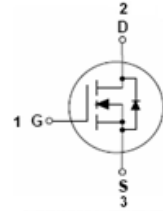


Features

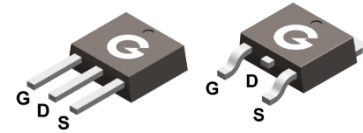
- Low on-resistance
- Low gate charge
- Extremely high dv/dt capability
- RoHS compliant with Halogen-free

HF



Mechanical Data

- Case: TO-251, TO-252
- Molding Compound: UL Flammability Classification Rating 94V-0
- Terminals: Matte tin-plated leads; solderability-per MIL-STD-202, Method 208



TO-251

TO-252

Ordering Information

Part Number	Package	Shipping Quantity	Marking Code
BL5N65I	TO-251	80 pcs / Tube	5N65I
BL5N65D	TO-252	80 pcs / Tube or 2500 pcs / Tape & Reel	5N65D

Maximum Ratings (@ T_C = 25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Drain-to-Source Voltage	V _{DSS}	650	V
Gate-to-Source Voltage	V _{GSS}	±30	V
Continuous Drain Current (T _C = 25°C)	I _D	5	A
Continuous Drain Current (T _C = 100°C)		3.1	
Pulsed Drain Current	I _{DM}	20	A
Single Pulse Avalanche Energy ^{*3}	E _{AS}	210	mJ
Power Dissipation (T _C = 25°C)	P _D	100	W
Operating Junction Temperature Range	T _J	-55 ~ +150	°C
Storage Temperature Range	T _{STG}	-55 ~ +150	°C

Thermal Characteristics

Parameter	Symbol	Min.	Typ.	Max.	Unit
Thermal Resistance Junction-to-Case	R _{θJC}	-	-	1.25	°C/W
Thermal Resistance Junction-to-Air ^{*1}	R _{θJA}	-	-	62	°C/W

Electrical Characteristics (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
Static Characteristics						
V_{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	650	-	-	V
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 650V, V_{GS} = 0V$	-	-	1	μA
I_{GSS}	Gate-Body Leakage Current	$V_{GS} = \pm 30V, V_{DS} = 0V$	-	-	± 100	nA
On Characteristics						
$R_{DS(ON)}$	Drain-Source On-resistance ^{*2}	$V_{GS} = 10V, I_D = 2.5A$	-	-	2.4	Ω
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250\mu A$	2	-	4	V
Dynamic Characteristics						
C_{ISS}	Input Capacitance	$V_{GS} = 0V$	-	610	-	pF
C_{OSS}	Output Capacitance	$V_{DS} = 25V$	-	53	-	
C_{RSS}	Reverse Transfer Capacitance	$f = 1MHz$	-	3.5	-	
Switching Characteristics						
$t_{d(ON)}$	Turn-on Delay Time ^{*4}	$V_{DD} = 325V$	-	14	-	ns
t_r	Turn-on Rise Time ^{*4}	$V_{GS} = 15V$	-	16	-	
$t_{d(OFF)}$	Turn-Off Delay Time ^{*4}	$I_D = 5A$	-	32	-	
t_f	Turn-Off Fall Time ^{*4}	$R_G = 10\Omega$	-	11	-	
Q_G	Total Gate-Charge	$V_{DD} = 520V$	-	14.5	-	nC
Q_{GS}	Gate to Source Charge	$V_{GS} = 10V$	-	3	-	
Q_{GD}	Gate to Drain (Miller) Charge	$I_D = 5A$	-	6.5	-	
Source-Drain Diode Characteristics						
V_{SD}	Diode Forward Voltage ^{*2}	$I_{SD} = 5A, V_{GS} = 0V$	-	-	1.4	V
t_{rr}	Reverse Recovery Time	$I_{SD} = 5A, V_R = 400V$	-	256	-	ns
Q_{rr}	Reverse Recovery Charge	$dI/dt = 100A/\mu s$	-	1.2	-	μC

Notes:

1. The data tested by surface mounted on a minimum recommended FR-4 board
2. The data tested by pulsed, pulse width $\leq 300\mu s$, duty cycle $\leq 2\%$
3. The E_{AS} data shows Max. rating. The test condition is $V_{DD} = 100V, V_{GS} = 15V, L = 50mH$
4. Guaranteed by design, not subject to production

Ratings and Characteristics Curves (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

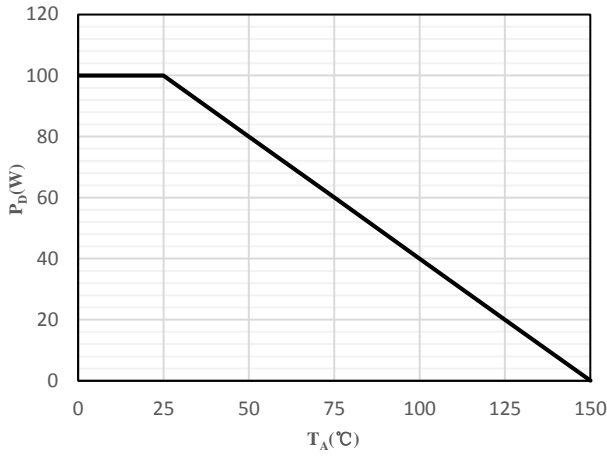


Fig 1 Power Dissipation

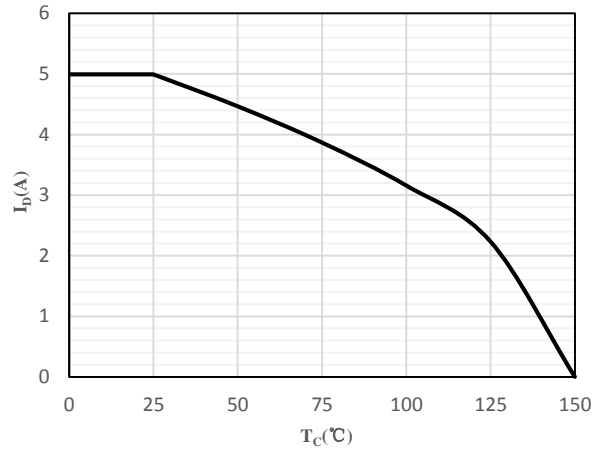


Fig 2 Drain Current

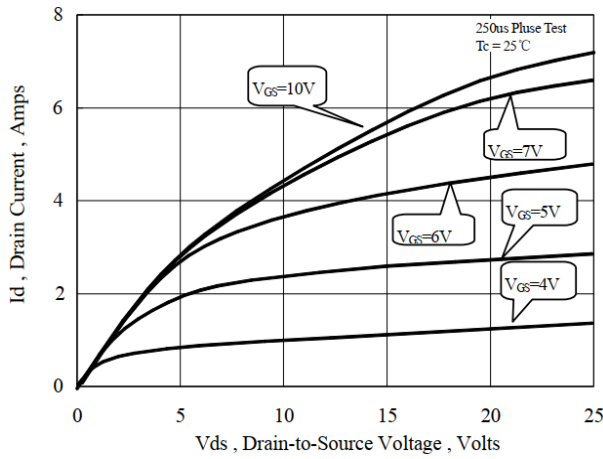


Fig 3 Typical Output Characteristics

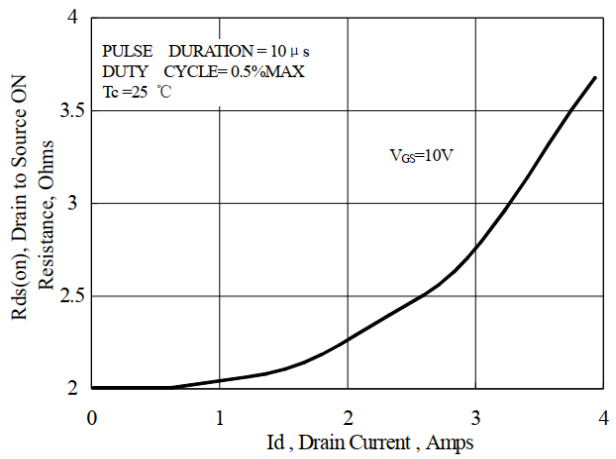


Fig 4 On-Resistance vs. Drain Current and Gate Voltage

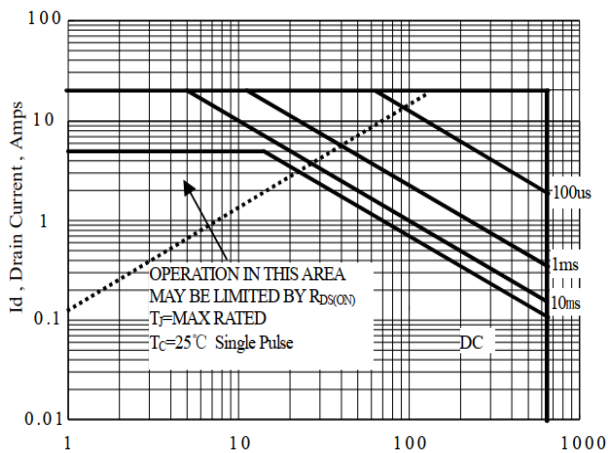


Fig 5 Safe Operation Area

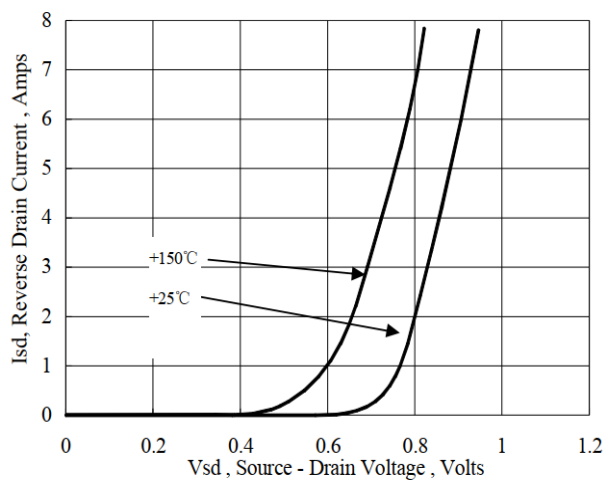


Fig 6 Body-Diode Characteristics

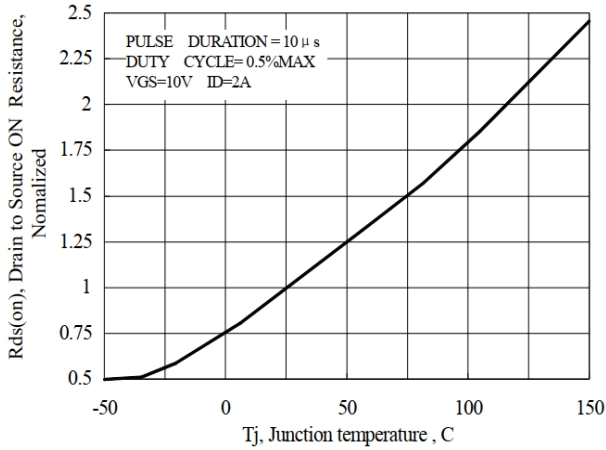


Fig 7 Normalized On-Resistance vs. Junction Temperature

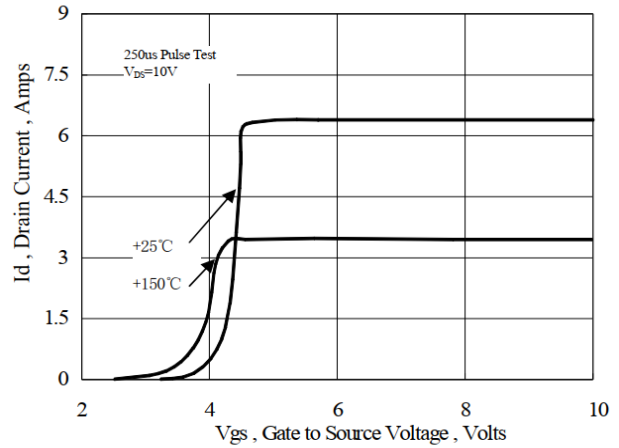


Fig 8 Transfer Characteristics

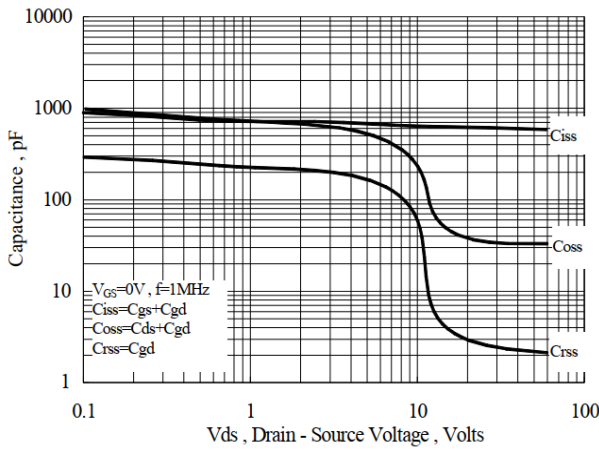


Fig 9 Capacitance Characteristics

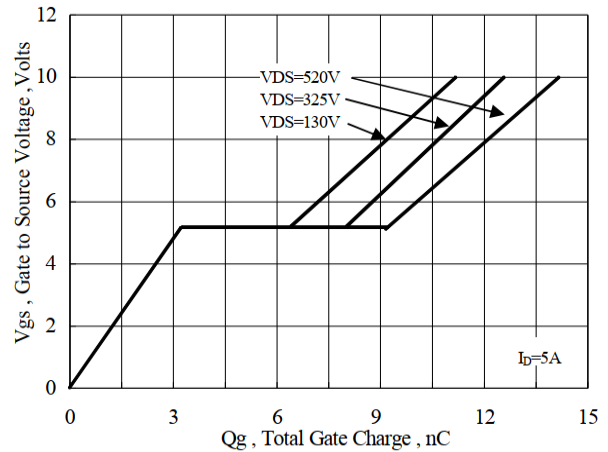


Fig 10 Gate-Charge Characteristics

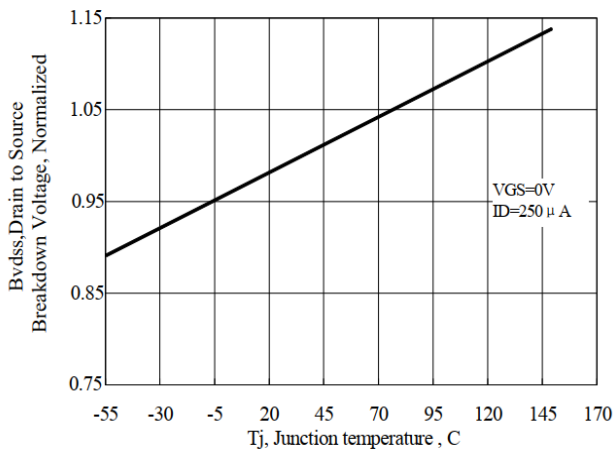


Fig 11 Normalized Breakdown Voltage vs. Junction Temperature

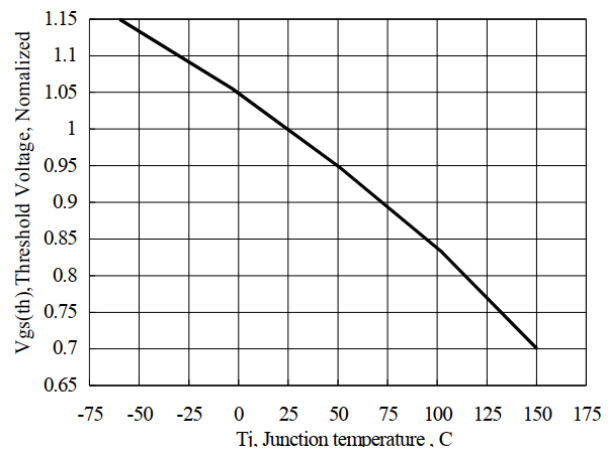
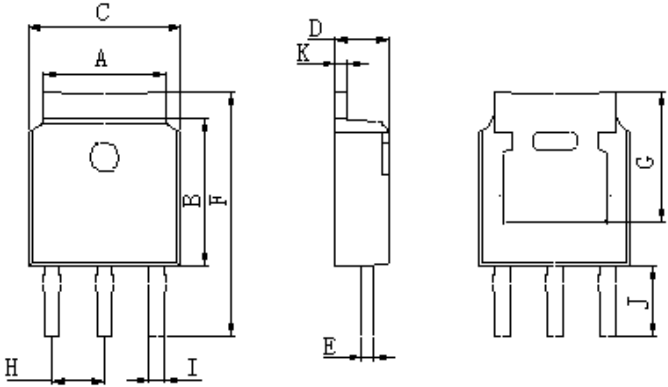
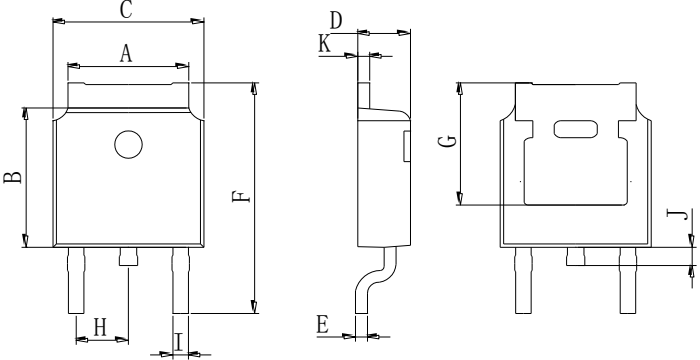


Fig 12 Normalized VGS(th) vs. Junction Temperature

Package Outline Dimensions (Unit: mm)

TO-251			
Dimension	Min.	Max.	
A	5.05	5.65	 <p>Diagram showing TO-251 package outline dimensions: A (width), B (height), C (total width), D (lead height), E (lead length), F (total height), G (lead width), H (lead spacing), I (lead width), J (lead length), K (lead thickness).</p>
B	5.80	6.40	
C	6.25	6.85	
D	2.20	2.40	
E	0.40	0.60	
F	11.00	11.60	
G	5.05	5.65	
H	2.10	2.50	
I	0.70	0.90	
J	4.00	4.40	
K	0.40	0.60	

TO-252			
Dimension	Min.	Max.	
A	5.05	5.65	 <p>Diagram showing TO-252 package outline dimensions: A (width), B (height), C (total width), D (lead height), E (lead length), F (total height), G (lead width), H (lead spacing), I (lead width), J (lead length), K (lead thickness).</p>
B	5.80	6.40	
C	6.25	6.85	
D	2.20	2.40	
E	0.40	0.60	
F	9.71	10.31	
G	5.05	5.65	
H	2.10	2.50	
I	0.70	0.90	
J	0.50	0.70	
K	0.40	0.60	

Mounting Pad Layout (Unit: mm)

